

1. General description

Planar passivated Silicon Controlled Rectifier with ultra-sensitive gate in a SOT54 (TO-92) plastic package.

2. Features and benefits

- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Ultra sensitive gate

3. Applications

- Electronic ballasts
- · Safety shut down and protection circuits
- Sensing circuits
- Smoke detectors
- Switched Mode Power Supplies

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage			-	-	600	V
V _{RRM}	repetitive peak reverse voltage			-	-	600	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>		-	-	8	Α
I _{T(AV)}	average on-state current	half sine wave; $T_{lead} \le 67 \text{ °C}$; Fig. 1		-	-	0.51	A
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{lead} \le 67 \text{ °C}$; Fig. 2; Fig. 3		-	-	0.8	A
Static chara	acteristics		1			1	
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>		0.5	-	7	μA





5. Pinning information

Table 2	. Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	А	anode		A - P+ K
2	G	gate		G sym037
3	К	cathode		
			TO-92 (SOT54)	

6. Ordering information

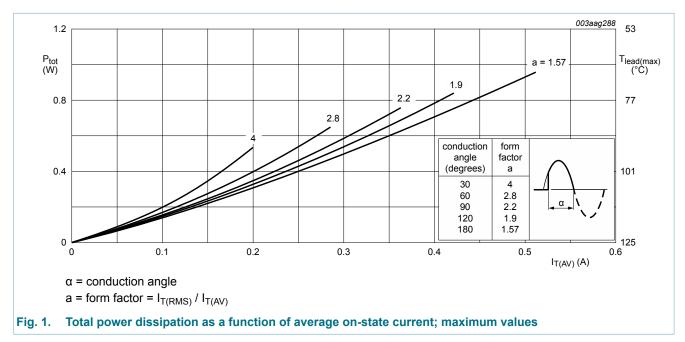
Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
N0118GA	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

7. Limiting values

Table 4.Limiting values

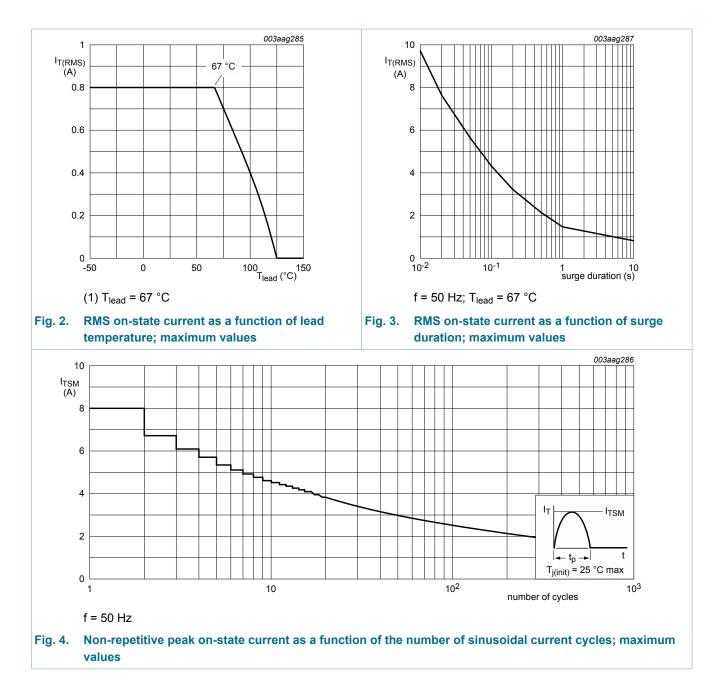
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
V _{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; $T_{lead} \le 67 \text{ °C}$; Fig. 1	-	0.51	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{lead} \le 67 \text{ °C}$; Fig. 2; Fig. 3	-	0.8	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 10 \text{ ms}; Fig. 4; Fig. 5$	-	8	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$	-	9	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.32	A ² s
dl _T /dt	rate of rise of on-state current	I_{T} = 0.8 A; I_{G} = 10 mA; dI_{G}/dt = 0.1 A/µs	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



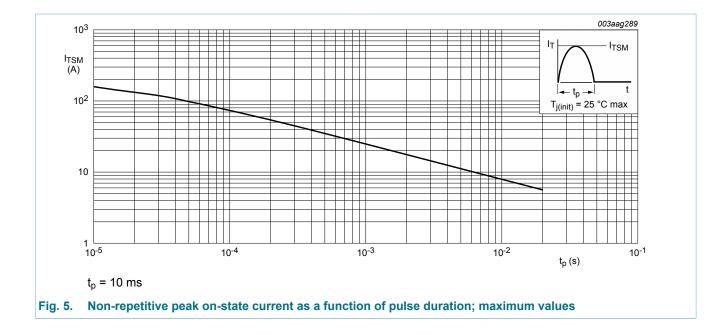
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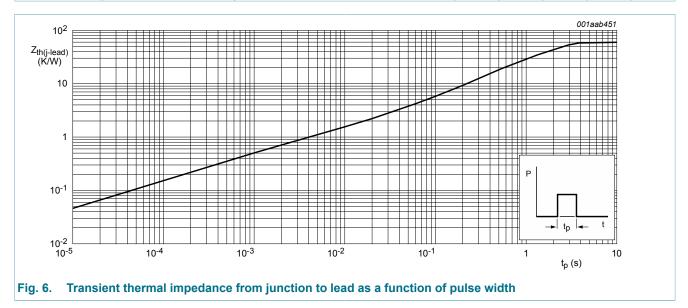
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8. Thermal characteristics

Table 5. T	hermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	<u>Fig. 6</u>	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W



9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static char	acteristics	· · · ·				_
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 7	0.5	-	7	μA
IL	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	-	6	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> ; <u>Fig. 10</u>	-	-	5	mA
V _T	on-state voltage	I _T = 1.6 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.4	1.95	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 12	-	-	0.8	V
I _D	off-state current	V _D = 400 V; T _j = 25 °C	-	-	10	μA
		$V_{\rm D}$ = 600 V; T _j = 125 °C; R _{GK} = 1 k Ω	-	-	100	μA
I _R	reverse current	V_{R} = 600 V; T _j = 25 °C; R _{GK} = 1 k Ω	-	-	10	μA
		V_{R} = 600 V; T _j = 125 °C; R _{GK} = 1 kΩ	-	-	100	μA
Dynamic cl	naracteristics	11				
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{R}_{\text{GK}} = 1 \text{k}\Omega;$ (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 13; Fig. 14	75	-	-	V/µs

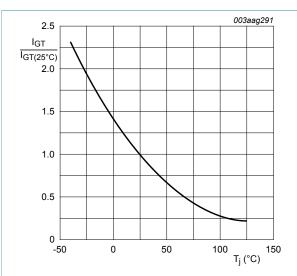
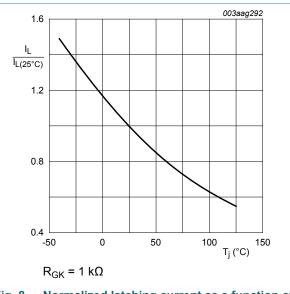


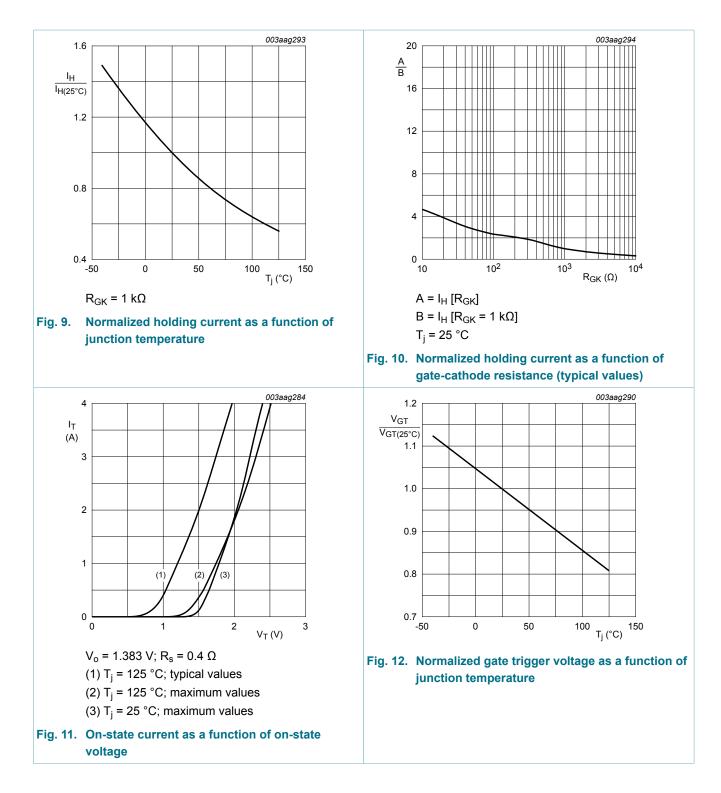
Fig. 7. Normalized gate trigger current as a function of junction temperature





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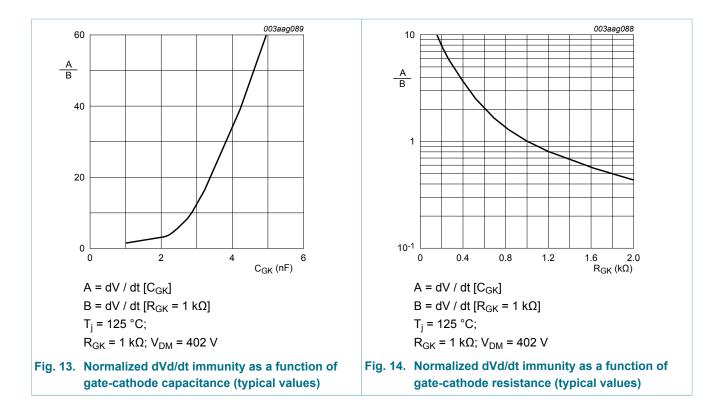
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10. Package outline

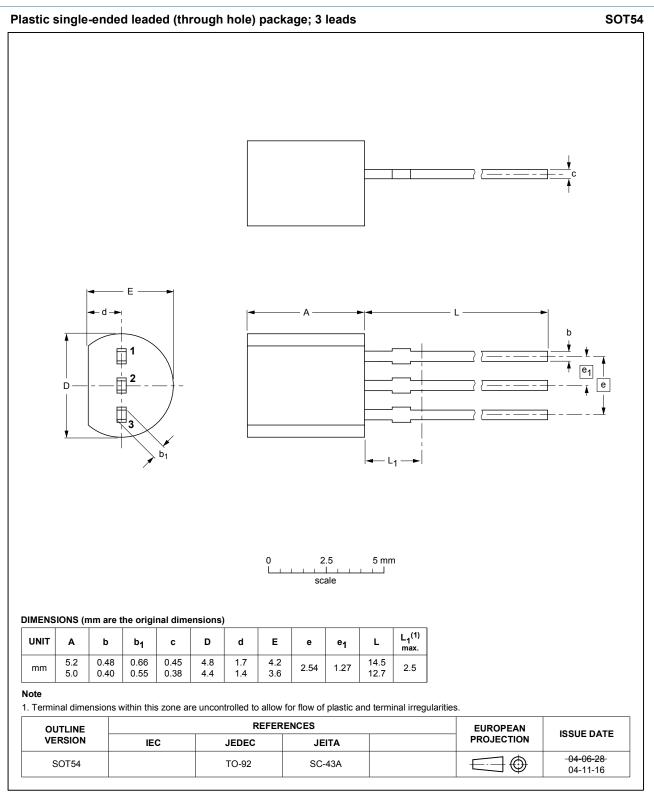


 Fig. 15.
 Package outline TO-92 (SOT54)

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 All

Product data sheet

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11. Legal information

11.1 Data sheet status

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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